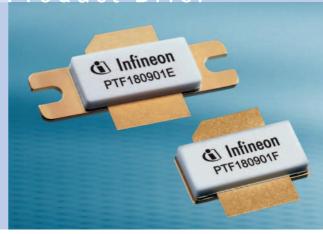
Product Brief



PTF180901

GSM/EDGE RF Power FET

The PTF180901

One of our new line of GSM/EDGE/CDMA2000 devices, the PTF180901 is optimized for the DCS and PCS bands. This device operates at 47% efficiency with 13.5 dB of gain and produces 115 W, P_{-1dB} . This high-gain high-efficiency device is ideal to power your amplifier design. A laterally diffused single-ended GOLDMOS® FET, it incorporates full gold metallization and integrated ESD protection to ensure excellent lifetime and reliability.

Features

- Optimized for bandwidths 1805 MHz 1880 MHz and 1930 MHz – 1990 MHz
- Improved ruggedness
- Broadband internal matching
- Full gold metallization
- Integrated ESD protection: Human Body Model, Class 1 (minimum)
- Excellent thermal stability
- Low HCI drift
- Capable of handling 10:1 VSWR@28 V, 90 W (CW) output power

Performance

- Typical EDGE performance
 - Average output power = 35 W
 - Gain = 14.5 dB
 - Efficiency = 32%
 - EVM = 1.7% AVG
 - ACPR@400 KHz = -60 dBc
 - ACPR@600 KHz = -74 dBc
- Typical two-tone performance
 - Output power = 90 W PEP
 - Gain = 15 dB
 - Efficiency = 36%
 - IM3 = -30 dBc
 - 1 MHz tone spacing

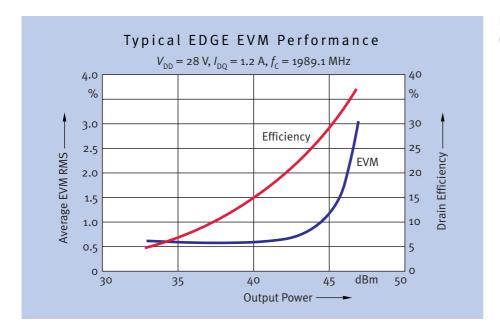
Type List

Туре	Output Power	Gain	Supply Voltage	Package Type	Package
PTF180901E	90 W	15 dB	28 V	Thermally enhanced	30248
PTF180901F	90 W	15 dB	28 V	Thermally enhanced,	31248
				earless	

www.infineon.com/wireless

Wireless Communication



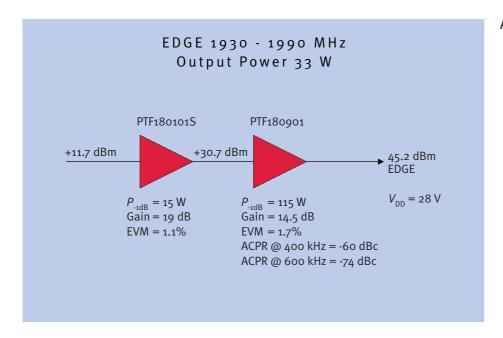


Performance Characteristics

Two-Tone Measurements

 $V_{\rm DD}$ = 28 V, $I_{\rm DQ}$ = 1.2 A, $P_{\rm OUT}$ = 90 W PEP, $f_{\rm C}$ = 1930 MHz, Tone Spacing = 100 kHz

Characteristic	Symbol	Min.	Typ.	Max.	Units
Gain	G_{ps}	14	15	-	dB
Drain Efficiency	$\eta_{ extsf{D}}$	30	36	_	%
Intermodulation Distortion	IMD	_	-30	-28	dBc



Application Example

How to reach us: http://www.infineon.com

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